

ECTHCAG24VUL

High Power TVS Diode

The ECTHCAG24VUL is a high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The ECTHCAG24VUL Series complies with the IEC 610002 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a 3pin DFN2020-3 package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multimedia card interfaces.

Features

- Protects one I/O lines
- Working voltages : 24V
- Low leakage current
- Response Time is $< 1\text{ ns}$
- Meets MSL 1 Requirements
- Solid-state silicon avalanche technology
- ROHS compliant



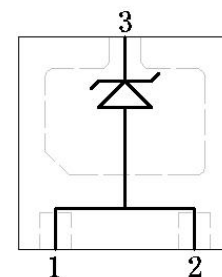
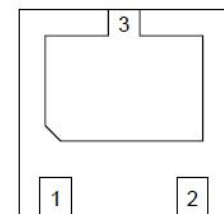
DFN2020-3L

Main applications

- Power Management
- Industrial Application
- Power Supply Protection

Protection solution to meet

- IEC61000-4-2 (ESD) $\pm 30\text{kV}$ (air), $\pm 30\text{kV}$ (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 150A (8/20 μs)



Ordering Information

Device	Mark	Qty per Reel	Reel Size
ECTHCAG24VUL	T24	3000	7 Inch

Maximum ratings (Temp=25°C Unless Otherwise Specified)

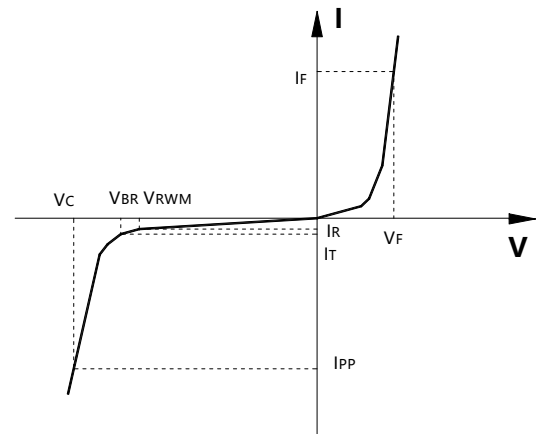
Parameter	Symbol	Value	Unit
ESD Rating per IEC61000-4-2:		30	
Contact		30	KV
Air		30	
Lead Soldering Temperature	T _L	260 (10 sec.)	°C
Operating Temperature Range	T _J	-55 ~ 150	°C
Storage Temperature Range	T _{STG}	-55 ~ 150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

*Other voltages may be available upon request.

1. Non-repetitive current pulse, per Figure 1.

Symbol	Parameter
V _{RWM}	Working Peak Reverse Voltage
V _{BR}	Breakdown Voltage @ I _T
V _C	Clamping Voltage @ I _{PP}
I _T	Test Current
I _{RM}	Leakage current at V _{RWM}
I _{PP}	Peak pulse current
C _O	Off-state Capacitance
C _J	Junction Capacitance

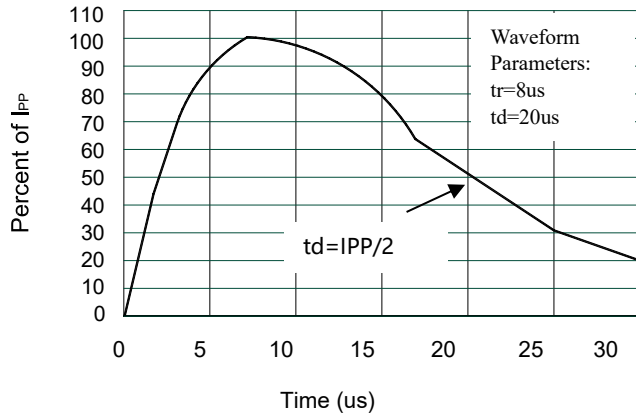


Electrical characteristics (Temp=25°C Unless Otherwise Specified)

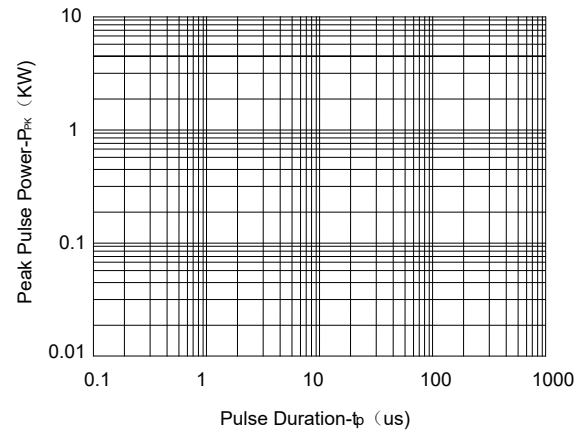
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V _{RWM}	Reverse Working Voltage	Pin 3 to pin 1,2			24	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA, Pin 3 to pin 1,2	25.7			V
I _R	Reverse Leakage Current	V _{RWM} = 24V, Pin 3 to pin 1,2			1	μA
V _C	Clamping Voltage	I _{PP} = 50A, t _p = 8/20μs, Pin 3 to pin 1,2		34.5		V
		I _{PP} = 80A, t _p = 8/20μs, Pin 3 to pin 1,2		38.6	45.5	V
C _J	Junction Capacitance	V _R = 0V, f = 1MHz, Pin 3 to pin 1,2		0.5		nF
P _{pp}	Peak Pulse Power	t _p = 8/20μs waveform		3000		W

Junction capacitance is measured in V_R=0V, F=1MHz

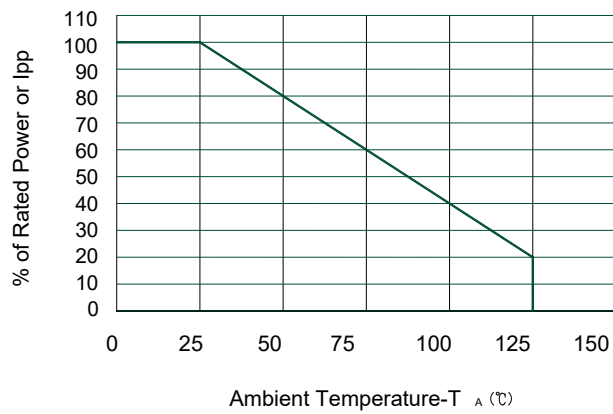
Typical electrical characterist applications



Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve

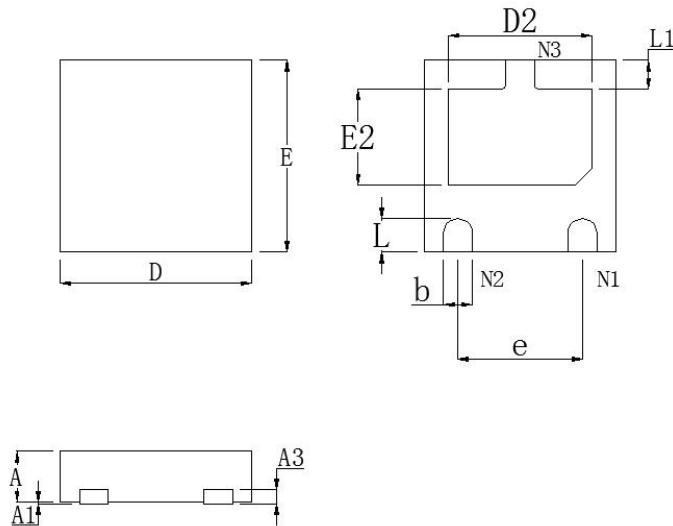
Package Information

DFN2020-3L

Mechanical Data

Case:DFN2020

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters		
	Min	Nom	Max
A	0.50	0.55	0.60
A1	0.00	—	0.05
A3	0.15 REF.		
D	1.95	2.00	2.05
E	1.95	2.00	2.05
b	0.25	0.30	0.35
L	0.30	0.35	0.40
L1	0.25	0.30	0.35
D2	1.35	1.50	1.60
E2	0.85	1.00	1.10
e	1.30 BSC		

Recommended Pad outline

